NSN 5961-01-231-9123

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View Online at https://aerobasegroup.com/nsn/5961-01-231-9123 **Inclosure Material:** Ceramic and metal **Overall Length:** 1.500 inches **Overall Height:** 0.430 inches **Overall Width:** 1.005 inches **Function For Which Designed:** Rectifier **End Application:** F-15 acft **Mounting Facility Quantity: Component Name And Quantity:** 4 semiconductor device diode **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 45.0 reverse voltage, peak all semiconductor device diode **Current Rating Per Characteristic:** 50.00 amperes source cutoff current preset all semiconductor device diode **Power Rating Per Characteristic:** 60.0 watts small-signal input power, common-collector preset all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Case contains beryllium oxide - handle and dispose iaw hazmat procedures **Precious Material And Location:** Plated case gold **Precious Material:** Gold **Test Data Document:** 82577-655365 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 8 uninsulated wire lead Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

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